The μ-flown: a novel device for measuring acoustic flows

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Abstract

An acoustic wave consists of two elements, the acoustic pressure and the acoustic flow. Up to now one has to measure the pressure and calculate the flow to determine the acoustic flow, so it would be convenient to have a sensor that is able to measure acoustic flows. At the University of Twente a novel device has been developed which fulfills this need. In this paper a short introduction to the governing principles of this dynamic flow sensor, the fabrication process, the electronics and some of its interesting applications will be presented. This micro-machined device measuring acoustic flows is called the microflown or μ-flown.

Keywords: Acoustic flow, Microflown

1. The acoustic flow sensor

The starting point of the investigation is the micro liquid flow sensor [1]. This sensor consists of three resistors located in the middle of a channel (Fig. 1). The two outermost resistors are used as sensors, while the resistor located in the middle is used as a heater. The dimensions of the sensor are in hundreds of micrometres. An applied flow causes a difference in temperature between the upstream and downstream sensors. The change of resistance in both resistors can be measured and leads to an electrical output proportional to the applied flow. While the displacement of the heated gas is measured, the sensitivity is inversely proportional to the frequency. Furthermore, the thermal time constant of the sensing elements will cause a sensitivity inversely proportional to the frequency. For low frequencies the dynamic model will converge to the (quasi-)static flow-sensor model. In contrast with the model of the static flow sensor [1], in which the gas flow transports the generated heat out of the system, there is no net heat transport in the model of the dynamic flow sensor.

Fig. 1. The μ-flown. The spacing between the Si₃N₄ bridges is 30 μm. The width of the sensors is 5 μm and the heater is 100 μm wide.

2. Acoustic theory

The acoustic domain can be described with two physical quantities, pressure and volume flow. However, in the field of acoustics the particle velocity is used instead of the volume flow.
flow. The particle velocity is defined as the volume flow divided by the surface in which the wave propagates. The ratio of the pressure and the particle velocity is the specific acoustic impedance \([2]\). The specific acoustic impedance for a number of typical cases will be discussed below.

The specific acoustic impedance of open air is given by \([2]\):

\[
Z_\infty = \frac{\rho c}{1 + i\omega/c},
\]

using \(\rho\) as the density of the medium, \(c\) the velocity of sound in the medium and \(r\) representing the distance to the acoustic source. For a frequency of 100 Hz the ratio \(c/\omega\) is 55 cm. For a larger radius Eq. (1) is simplified to \(Z_\infty = \rho c\).

Another case is a short tube with an acoustic source on one side and on the other a stiff, reflecting wall. The acoustic impedance in the tube in the longitudinal axis is dependent on both frequency and position \([2]\).

The third environment is a tube of an infinite length. In practice the length will be finite, but it can still be used if the measurement takes place before the first reflection reaches the measuring point. The specific acoustic impedance of an infinite tube is \([3]\)

\[
Z_\infty = \rho c (2)
\]

In order to calibrate the \(\mu\)-flown, a micromachined device for measuring acoustic flows, it has to be remembered that this is a new device, so a reference \(\mu\)-flown is not available. The solution of this problem has been found in using a reference pressure microphone and Eq. (2). This impedance is independent of position and frequency, which makes it well suited for transfer-function measurements.

The last definition we would like to present here is the intensity. Intensity equals the product of the pressure and the particle velocity. Therefore it is a vector and related to the propagation of the power incorporated in an acoustic wave.

**3. Boundary conditions for plane-wave propagation in a cylindrical tube**

For frequencies lower than \(f_c\), called the cut-off frequency, only plane waves exist and non-plane waves vanish exponentially \([4]\). The cut-off frequency is given by

\[
f_c = \frac{c}{dl}.71
\]

where \(d\) is the diameter of the tube.

Other types of waves are generated when the tube starts to resonate in the radial-circumferential flexural mode \([5]\). This effect is neglected here. In order to make a plane-wave approximation, the viscous boundary layers should be thin \([4]\):

\[
f_{\text{min}} \approx \frac{2\nu}{nd^2}
\]

where \(\nu\) represents the kinematic viscosity of air.

Because of the finite length of a tube and the reflections at the end, the lowest frequency that can be measured is

\[
f_{\text{min}} = \frac{c}{2l}
\]

where \(l\) is the length of the tube.


The Gadget is a new type of circuit especially designed to measure the small differential resistor variations of the \(\mu\)-flown (Fig. 2).

The transfer function of the Gadget is \([6]\)

\[
\Delta V_{\text{out}} = 2IR \frac{\Delta R_{\text{diff}}}{R}
\]

in which \(\Delta V_{\text{out}}\) is the a.c. variation in the output voltage as a result of \(\Delta R_{\text{diff}}\), the differential resistance variation of \(R\), the initial value of the \(\mu\)-flown resistor. The d.c. bias current \(I\) is defined as

\[
I = E - U_{\text{BE}} \frac{R_t + R}{R_t}
\]

in which \(E\) is the power-supply voltage and \(U_{\text{BE}}\) the base-emitter voltage (\(U_{\text{BE}} = 0.6-0.7\) V). The d.c. bias condition of the Gadget is

\[
V_{\text{out}} = E - IR_2 > U_{E,72} + U_{C E,\text{min}} = U_B
\]

Substituting Eq. (7) in Eq. (8), the d.c. bias condition yields

\[
R_t > R_2
\]

The d.c. output voltage is

\[
V_{\text{out,d.c.}} = E - IR_2
\]

![Fig. 2. Measuring electronics: the Gadget.](image-url)
The signal-to-noise ratio of the Gadget is [6]

\[
\frac{S}{N}_{\text{Gadget}} = \frac{1}{2IR} \frac{\Delta R}{R} \left[ q \cdot BW \left( 2U_T \left( \frac{T_s}{T} + \frac{r_{nb}}{R} \right) \right) + \frac{U_T}{IR} + \frac{U_T}{2\alpha_{\text{FE}} \left( \frac{r_{nb}}{R} + 2 \right)} + \frac{IR}{\alpha_{\text{FE}}} \left( 1 + \left( 1 + \frac{r_{nb}}{R} \right)^2 \right) \right]^{1/2}
\]

in which \( q \) is the charge of an electron, BW the bandwidth of the signal, \( U_T \) the thermal voltage (25 mV), \( T_s \) the sensor temperature, \( T \) ambient temperature, \( r_{nb} \) the base series resistance of the used bipolar junction transistor (BJT) and \( \alpha_{\text{FE}} \) the d.c. forward current gain.

The Gadget Duo Sensation (Fig. 3) consists of two Gadgets. It is capable of measuring the sum signal of two \( \mu \)-flows at the same time and can be used with either voltage or current output.

Using this Gadget in the current-output mode, the input of the next electronics has to be of low impedance and have a voltage of 0.5E. The output current is

\[
\Delta I_{\text{out}} = 2I \left( \frac{\Delta R}{R} \right)_2 - 2 \left( \frac{\Delta R}{R} \right)_1
\]

The bias current is given by

\[
l = \frac{E - 2U_{\text{RE}}}{2R + R_C}
\]

For voltage output the following electronics has to be of high input impedance. The PNP-Gadget is an active load [7] for the NPN-Gadget and vice versa. This way it is possible to get a large transfer function with a relatively low power-supply voltage. If \( U_{\text{out}} \approx E/2 \), the transfer function is

\[
\Delta U_{\text{out}} = \Delta I_{\text{out}} \left( r_{\text{NPN}} \mid r_{\text{PNP}} \right) = \frac{U_{\text{A}_{\text{NPN}}}U_{\text{A}_{\text{NPN}}} \Delta I_{\text{out}}}{U_{\text{A}_{\text{NPN}}} + U_{\text{A}_{\text{NPN}}}}
\]

using \( U_A \) as the Early voltage and \( r_e \) is the output voltage of a BJT. Note that this transfer function is independent of the bias current. The signal-to-noise ratio is approximately the same as Eq. (11).

5. The fabrication process

The method that we are using to manufacture the \( \mu \)-flow is a derivative of the process for the flow sensor as described in Ref.[1]. The process is relatively simple and straightforward. We use low-pressure chemical-vapour deposition techniques to deposit the layers and reactive ion etching to perform dry etching. We start with a silicon wafer of 380 \( \mu \)m thickness. First we deposit a polysilicon layer, which will be used as a sacrificial layer. After patterning by photolithography and dry etching, we deposit a silicon nitride layer. This layer is also patterned by photolithography and dry etched. The next step is carried out by deposition of the metal layer by sputtering. The metals that we use are chromium and gold. The pattern in the metal layer is not created by etching but with lift-off. The last step in the process is the etching of the channel. The silicon wafer is already patterned with the silicon nitride layer and we use a KOH solution to etch an approximately 300 \( \mu \)m deep channel. This wet-etching method is anisotropic and gives defined channel walls, but a time stop is needed to define the depth of the channel. After the wet etching the samples have to be sawed, mounted and bonded.

6. Measurements

Measurements of the described acoustic phenomena have been performed with the \( \mu \)-flow in combination with a conventional pressure microphone. The experimental set-up consists of a 20 m long tube in which the \( \mu \)-flow and a reference microphone are mounted, see Fig. 4. By generating a burst and measuring within a specific time span, the influence of reflections can be avoided.

In an acoustic wave a pressure wave and a flow wave are inextricably related. Figs. 5 and 6 show how the pressure and flow are altered after reflection. The first bursts are generated...
Fig. 5. Acoustic response of a rigidly closed tube: phase shift after reflection in particle flow and no phase shift in pressure.

![Graph](image1.png)

Fig. 6. Acoustic response of an open tube: phase shift after reflection in pressure and no phase shift in particle flow.

![Graph](image2.png)

Fig. 7. Sound intensity of a forward and backward propagating wave in a rigidly closed tube.

![Graph](image3.png)

by forward propagating waves while the second bursts are generated by backward propagating waves.

Another good example of what is possible with the combination of microphone and \( \mu \)-flow is shown in Fig. 7: while the intensity of the forward propagating wave is positive, the intensity of the backward propagating wave is negative.

The sensitivity, i.e., the ratio of the output voltage and the applied particle velocity, of the \( \mu \)-flow is shown in Fig. 8. The acoustic impedance is \( \rho c = 448 \) kg m\(^{-2}\) s\(^{-1}\) thus a sound pressure level of 60 dB, which equals 0.02 Pa, will result in a particle velocity of 45 \( \mu \)m s\(^{-1}\).

The output of a set of two \( \mu \)-flows in combination with a Gadget Duo Sensation (Fig. 3) as a function of the acoustic pressure applied was measured by a frequency of 100 Hz (Fig. 9). The power-supply voltage, \( E \), was 40 V and both sensor and heater currents were 10 mA. An output of 2 mV, which equals a sound pressure level of 50 dB, could be measured.

A different set-up is used in the next measurement: a 40 m long tube with a loudspeaker at each end (Fig. 10).

One speaker generates a 150 Hz burst and the other a 200 Hz burst. The \( \mu \)-flow and microphone are situated in the middle, measuring both acoustic waves travelling in opposite directions (upper two curves, Fig. 11).

Because in forward and backward travelling waves the particle flow is 180° phase shifted, the sum signal of the upper

![Graph](image4.png)

Fig. 8. Sensitivity of the \( \mu \)-flow. The shs configuration was used. The sensor and heater current were each 10 mA.

Fig. 9. The output of two \( \mu \)-flows in combination of a Gadget Duo Sensation as a function of the acoustic pressure for a frequency of 100 Hz.

![Measurement set-up](image5.png)

Fig. 10. Measurement set-up II.
two curves results in the forward travelling wave. The backward travelling wave is obtained by subtracting the output of the \( \mu \)-flow from the output of the pressure microphone.

7. Multiple configurations

In the applied set-up multiple configurations of the dynamic flow sensor are possible. The above-mentioned configuration is called a sensor heater sensor (shs) type of \( \mu \)-flow, describing the geometrical structure. Other possible configurations are sensor sensor (ss) and sensor heater (sh); see Fig. 12.

It is possible to create a microflow with only two sensors, both heated by a current. This type of \( \mu \)-flow has two fundamental advantages: the structure is simplified and measurements with a larger current gives a larger sensitivity to the applied acoustic flow. Furthermore, only one sensor with a heater appears to perform. It is basically a hot-wire anemometer [8] but enhanced with a heater nearby. The interesting features of this type of \( \mu \)-flow are the fact that the output increases with the applied heater current and the possibility, in contrast to the hot-wire anemometer, of detecting the direction of the flow (Fig. 13). The characteristic double frequency of a hot-wire anemometer vanishes with the increasing heater current.

A remark about the configurations: it is possible to enlarge the sensor current. This causes the temperature of the sensor to rise and an increase of the sensitivity \((\Delta R/R)\) of the various types of \( \mu \)-flow. A sensor is called a hot sensor when its heat production is not negligible compared with that of the heater. In order to compare the various \( \mu \)-flow types, the sensitivity is a convenient value and is defined as the output of the \( \mu \)-flow \((\Delta R/R \) in promille) at a frequency of 100 Hz.

Table 1

<table>
<thead>
<tr>
<th>Sensor current (mA)</th>
<th>shs</th>
<th>ss</th>
<th>sh</th>
</tr>
</thead>
<tbody>
<tr>
<td>2.5</td>
<td>0.17%</td>
<td>N.A.</td>
<td>0.05%</td>
</tr>
<tr>
<td>10</td>
<td>0.3%</td>
<td>0.17%</td>
<td>0.08%</td>
</tr>
</tbody>
</table>

8. Applications

The combination of a dynamic flow sensor and a pressure sensor opens up a range of possible applications. With this set-up it is possible to perform an analysis of the direction of energy in both gases and liquids (Fig. 7). By subtracting and adding the adjusted signals of a \( \mu \)-flow and pressure microphone, one can derive a stereo signal measured at one point. Another application is the measurement of the impedance in a system filled with liquid or gas, which gives information about the density and viscosity. Finally, a completely different application may be the use of a \( \mu \)-flow as a feedback sensor in a loudspeaker system.

9. Conclusions

We have developed a small and easy-to-operate dynamic flow sensor, the \( \mu \)-flow. When using it, one has to take into account the \( 1/f \) behaviour. A significant improvement of the sensitivity of the complete device is to be expected from the combination of the \( \mu \)-flow and the Wheatstone Gadget, when used in other configurations. The \( \mu \)-flow makes it possible to measure the particle velocity of an acoustic wave.
In combination with a microphone, it is possible to determine the direction of propagation of an acoustic wave.

10. Further research

Our priority is to develop a more detailed analytical model, and to gain more insight into the temperature distribution. Finite-element simulations will also be done.

With this insight it should be possible to design a more optimal $\mu$-flow with regard to the transfer function (increasing $\Delta R/R$). So far we have only investigated the constant-power principle; next we are going to investigate the constant-temperature principle.

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References


Biographies

H.-E. de Bree studied electrical engineering at the University of Twente in Enschede. In 1994 he graduated from the Integrated Circuits and Electronics group. At the moment he is working for his Ph.D. at the Transducers and Materials Science group. In February 1994 he invented the $\mu$-flow.

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